TOSHIBA TRANSISTOR SILICON PNP EPITAXIAL TYPE (PCT PROCESS)

# 2 S A 1 7 3 5

### **POWER AMPLIFIER APPLICATIONS**

#### **POWER SWITCHING APPLICATIONS**

• Low Saturation Voltage : VCE (sat) = -0.5V (Max.)

 $(I_C = -500 \text{mA})$ 

• High Speed Switching Time:  $t_{stg} = 0.25 \mu s$  (Typ.)

• Small Flat Package

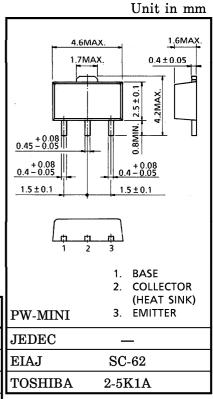
• P<sub>C</sub>=1~2W (Mounted on Ceramic Substrate)

• Complementary to 2SC4540

#### MAXIMUM RATINGS (Ta = 25°C)

| CHARACTERISTIC              | SYMBOL             | RATING  | UNIT |
|-----------------------------|--------------------|---------|------|
| Collector-Base Voltage      | $v_{\mathrm{CBO}}$ | -60     | V    |
| Collector-Emitter Voltage   | $v_{CEO}$          | -50     | V    |
| Emitter-Base Voltage        | $v_{\mathrm{EBO}}$ | -6      | V    |
| Collector Current           | $I_{\mathbf{C}}$   | -1      | Α    |
| Base Current                | $I_{B}$            | -0.2    | Α    |
| Collector Power Dissipation | $P_{\mathbf{C}}$   | 500     | mW   |
| Collector Power Dissipation | PC*                | 1000    | mW   |
| Junction Temperature        | Tj                 | 150     | °C   |
| Storage Temperature Range   | $\mathrm{T_{stg}}$ | -55~150 | °C   |
|                             |                    |         |      |

\* : Mounted on ceramic substrate (250mm $^2 \times 0.8t$ )



Weight: 0.05g

Marking

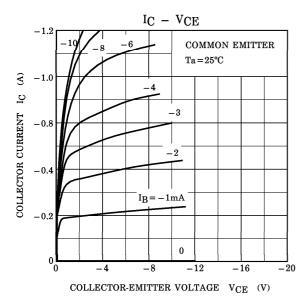


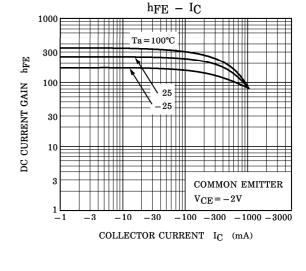
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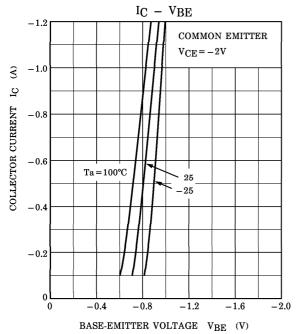
## ELECTRICAL CHARACTERISTICS (Ta = 25°C)

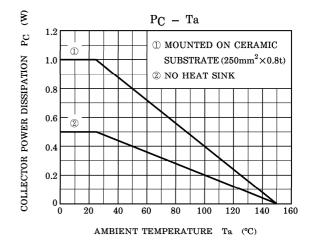
| CHARAC                           | TERISTIC     | SYMBOL                | TEST CONDITION  | MIN. | TYP. | MAX. | UNIT    |
|----------------------------------|--------------|-----------------------|---|------|------|------|---------|
| Collector Cut-o                  | off Current  | $I_{CBO}$             | $V_{CB} = -60V, I_{E} = 0$  | _    | _    | -0.1 | $\mu$ A |
| Emitter Cut-of                   | f Current    | $I_{EBO}$             | $V_{EB} = -6V, I_C = 0$   | _    | _    | -0.1 | $\mu$ A |
| Collector-Emit<br>Breakdown Vo   |              | V (BR) CEO            | $I_{C} = -10 \text{mA}, I_{B} = 0$  | -50  | _    | _    | V       |
| DC Current Gain                  |              | h <sub>FE (1)</sub>   | $V_{CE} = -2V, I_{C} = -100 mA$   | 120  | _    | 400  |         |
|                                  |              | h <sub>FE (2)</sub>   | $V_{CE} = -2V, I_{C} = -700 mA$   | 40   | _    | _    |         |
| Collector-Emit<br>Saturation Vol |              | V <sub>CE</sub> (sat) | $I_C = -500 \text{mA}, I_B = -25 \text{mA}$   | _    | _    | -0.5 | V       |
| Base-Emitter<br>Saturation Vol   | tage         | V <sub>BE</sub> (sat) | $I_C = -500 \text{mA}, I_B = -25 \text{mA}$   | _    | _    | -1.2 | V       |
| Transition Fre                   | quency       | $\mathbf{f_T}$        | $V_{CE} = -2V, I_{C} = -100 \text{mA}$  | _    | 100  | _    | MHz     |
| Collector Output Capacitance     |              | $C_{ob}$              | $V_{CB} = -10V, I_E = 0, f = 1MHz$  | _    | 16   | _    | pF      |
| Switching<br>Time                | Turn-on Time | ton                   | $I_{B1} \underbrace{\begin{matrix} I_{B2} \\ I_{B1} \end{matrix} \begin{matrix} I_{B2} \\ I_{B2} \end{matrix} \begin{matrix} I_{B2} \\ I_{B1} \end{matrix} \begin{matrix} I_{B2} \\ I_{B2} \end{matrix} \begin{matrix} I_{B2} \\ I_{B1} \end{matrix} \begin{matrix} I_{B2} \\ I_{B2} \end{matrix} \begin{matrix} I_{B2} \\ I_{B1} \end{matrix} \begin{matrix} I_{B2} \\ I_{B2} \end{matrix} \begin{matrix} I_{B2} \\ I_{B1} \end{matrix} \begin{matrix} I_{B2} \\ I_{B2} \end{matrix} \begin{matrix} I_{B2} \\ I_{B2} \end{matrix} \begin{matrix} I_{B2} \\ I_{B2} \end{matrix} \begin{matrix} I_{B2} \\ I_{B1} \end{matrix} \begin{matrix} I_{B2} \\ I_{B2} \end{matrix} \end{matrix} \begin{matrix} I_{B2} \\ I_{B2} \end{matrix} \begin{matrix} I_{B2} \\ I_{B2} \end{matrix} \end{matrix} \begin{matrix} I_{B2} \\ I_{B2} \end{matrix} \begin{matrix} I_{B2} \\ I_{B2} \end{matrix} \end{matrix} \end{matrix} \begin{matrix} I_{B2} \\ I_{B2} \end{matrix} \end{matrix} \begin{matrix} I_{B2} \\ I_{B2} \end{matrix} \end{matrix} \end{matrix} \end{matrix} \end{matrix} \begin{matrix} I_{B2} \\ I_{B2} \end{matrix} \end{matrix} \end{matrix} \end{matrix} \end{matrix} \begin{matrix} I_{B2} \\ I_{B2} \end{matrix} \end{matrix} \end{matrix} \end{matrix} \end{matrix} \end{matrix} \begin{matrix} I_{B2} \\ I_{B2} \end{matrix} \end{matrix} \end{matrix} \end{matrix} \end{matrix} \end{matrix} \begin{matrix} I_{B2} \\ I_{B2} \end{matrix} \end{matrix} \end{matrix} \end{matrix} \end{matrix} \end{matrix} \end{matrix} \begin{matrix} I_{B2} \\ I_{B2} \end{matrix} \end{matrix} \end{matrix} \end{matrix} \end{matrix} \end{matrix} \end{matrix} \end{matrix} \begin{matrix} I_{B2} \\ I_{B2} \end{matrix} \begin{matrix} I_{B2} \\ I_{B2} \end{matrix} \end{matrix}$ | _    | 0.1  | _    |         |
|                                  | Storage Time | $t_{\mathrm{stg}}$    |   | _    | 0.25 | _    | $\mu$ s |
|                                  | Fall Time    | tf                    |   | _    | 0.1  | _    |         |

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